L Number	Hits	Search Text	DB	Time stamp	
1	7	(phosphorus with (insulat\$3 dielectric))	USPAT;	2003/04/07 0	7:42
		and electron and 313/309-311,495-497.ccls.	EPO; JPO;		
			DERWENT		
2	32	((phosphorus with (insulat\$3 dielectric))	USPAT;	2003/04/07 0	07:45
		bpsg) and electron and	EPO; JPO;		
		313/309-311,495-497.ccls.	DERWENT		
3	1	(phosphorus with "sio.sub.2") and electron	USPAT;	2003/04/07 0	07:49
		and 313/309-311,495-497.ccls.	EPO; JPO;		
			DERWENT	0000/04/07/0	
4	23	(phosphor\$2 with "sio.sub.2") and electron	USPAT;	2003/04/07 0	37:59
		and 313/309-311,495-497.ccls.	EPO; JPO;		
_			DERWENT	2002/04/07 (20.00
5	32	((phosphorus phosphor) with ("silicon	USPAT;	2003/04/07 0	38:00
		dioxide" silica "sio.sub.2")) and electron	EPO; JPO; DERWENT		
6 .	12	and 313/309-311,495-497.ccls. (((phosphorus phosphor) with ("silicon	USPAT;	2003/04/07 0	าลงกก
0 .	12	dioxide" silica "sio.sub.2")) and electron	EPO; JPO;	2003/04/07	30.00
	•	and 313/309-311,495-497.ccls.) not	DERWENT		
		((phosphor\$2 with "sio.sub.2") and	DEKWENI		
		electron and 313/309-311,495-497.ccls.)			
13	. 2	6208071.pn.	USPAT;	2003/04/07 0	18:31
13	2	0200071.pii.	EPO; JPO;	2003/01/07	
			DERWENT		
_	0	313/309-311,495-497	USPAT;	2003/04/07 0	00:08
	1	010,000 011,100 10,	EPO; JPO;		
		,	DERWENT		
_	3661	313/309-311,495-497.ccls.	USPAT;	2003/04/07 0	00:08
	3001	313,303 311,130 131.0020.	EPO; JPO;		
			DERWENT		
ļ <u>_</u>	41	313/309-311,495-497.ccls. and ("SiO.sub.2"	USPAT;	2003/04/07 0	00:12
		silica "silicon oxide") and ("stannic	EPO; JPO;		
		oxide" "tin oxide" "SnO.sub.2") and	DERWENT		
		(substrate near9 (sodium na))			
-	24	313/309-311,495-497.ccls. and ("SiO.sub.2"	USPAT;	2003/04/07 (00:12
		silica "silicon oxide") and ("stannic	EPO; JPO;		
		oxide" "tin oxide" "SnO.sub.2") and	DERWENT	•	
ľ		(substrate near9 (sodium na)) and nm			
-	23	313√309-311,495-497.ccls. and ("SiO.sub.2"	USPAT;	2003/04/07 0	00:30
		silica "silicon oxide") and ("stannic	EPO; JPO;		
		oxide" "tin oxide" "SnO.sub.2") and	DERWENT		
		(substrate near9 (sodium na)) and nm and		,	
		electron		0000/04/07	20 20
-	21	313/309-311,495-497.ccls. and ("SiO.sub.2"	USPAT;	2003/04/07 (J2:38
		silica "silicon oxide") and ("stannic	EPO; JPO;		
		oxide" "tin oxide" "SnO.sub.2") and	DERWENT		
		(substrate near9 (sodium na)) and nm and			
_	0	electron and particle 313/309-311,495-497.ccls. and ("SiO.sub.2"	USPAT;	2003/04/07 0	00.31
-		silica "silicon oxide") and ("stannic	EPO; JPO;		
		oxide" "tin oxide" "SnO.sub.2") and	DERWENT		
		(substrate near9 (sodium na)) and nm and		- Control of the Cont	
		electron and particle and platinum and			
-		silver			:
-	21	313/309-311,495-497.ccls. and ("SiO.sub.2"	USPAT;	2003/04/07 0	02:18
		silica "silicon oxide") and ("stannic	EPO; JPO;		
		oxide" "tin oxide" "SnO.sub.2") and	DERWENT		
		(substrate near9 (sodium na)) and nm and			
		particle			
-	0	313/309-311,495-497.ccls. and ("SiO.sub.2"	USPAT;	2003/04/07 (00:42
		silica "silicon oxide") and ("stannic	EPO; JPO;		<i>_</i>
1		oxide" "tin oxide" "SnO.sub.2") and	DERWENT		
		(substrate near9 (sodium na)) and nm and			
		particle and phosphorous			
-	0	313/309-311,495-497.ccls. and ("SiO.sub.2"	USPAT;	2003/04/07 0	00:
		silica "silicon oxide") and ("stannic	EPO; JPO;		Å P
		oxide" "tin oxide" "SnO.sub.2") and	DERWENT		
		(substrate near9 (sodium na)) and nm and			ļ
L		particle and phosphorus	L	<u> </u>	

Search History 4/7/03 9:25:37 AM Page 1

الم والمنت

-	81	phosphorus and (insulat\$3 dielectric) and	USPAT;	2003/04/07 0	0:43
		electron and 313/309-311,495-497.ccls.	EPO; JPO;		
			DERWENT	•	
_	21	(phosphorus same (insulat\$3 dielectric))	USPAT;	2003/04/07 0	7:35
		and electron and 313/309-311,495-497.ccls.	EPO; JPO;		
		· · ·	DERWENT		
_	21	313/309-311,495-497.ccls. and ("SiO.sub.2"	USPAT;	2003/04/07 0	1:19
		silica "silicon oxide") and ("stannic	EPO; JPO;	, ,	
		oxide" "tin oxide" "SnO.sub.2") and	DERWENT		
		(substrate near9 (sodium na)) and nm and			
		particle and matrix			
_	21	313/309-311,495-497.ccls. and ("SiO.sub.2"	USPAT;	2003/04/07 0	1:55
	21	silica "silicon oxide") and ("stannic	EPO; JPO;	2003,01,01	1.00
		oxide" "tin oxide" "SnO.sub.2") and	DERWENT		
	1	(substrate near9 (sodium na)) and nm and	DERWEIT		
	1	particle and matrix and (pt platinum) and			
		(ag silver)			
	21	' =	USPAT;	2003/04/07 0	1.55
-		silica "silicon oxide") and ("stannic	EPO; JPO;	2003/04/07 0	1.33
	1		DERWENT		
		oxide" "tin oxide" "SnO.sub.2") and	DERWENT		
		(substrate near9 (sodium na)) and nm and			
		particle and matrix and (pt platinum) and		_	
		(ag silver) and flat\$5		0000/04/07 0	2.10
-	3	313/309-311,495-497.ccls. and ("SiO.sub.2"	USPAT;	2003/04/07 0	2:18
		silica "silicon oxide") same ("stannic	EPO; JPO;		
		oxide" "tin oxide" "SnO.sub.2") and	DERWENT		
		(substrate near9 (sodium na)) and nm and			
	[particle			
-	2	5872541.pn.	USPAT;	2003/04/07 0	2:38
			EPO; JPO;		
	1		DERWENT		i
-	8	'	USPAT	2003/04/07 0	3:49
		"3725731" "3735186" "4093562"			
		"4303917" "4325084").PN.			
_	4	5872541.URPN.	USPAT	2003/04/07 0	3:52

